

### STP40NF10L

### N-channel 100V - 0.028Ω - 40A TO-220 Low gate charge STripFET™ Power MOSFET

#### **General features**

Туре	V <sub>DSS</sub>	V <sub>DSS</sub> R <sub>DS(on)</sub>		
STP40NF10L	100V	<0.033Ω	40A	

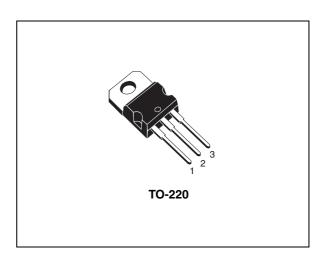
- Exceptional dv/dt capability
- 100% avalanche tested
- Application oriented characterization

#### **Description**

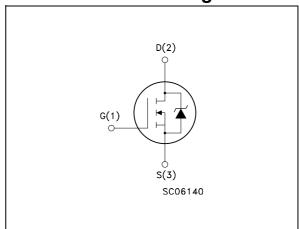
This Power MOSFET series realized with STMicroelectronics unique STripFET process has specifically been designed to minimize input capacitance and gate charge. It is therefore suitable as primary switch in advanced highefficiency isolated DC-DC converters for Telecom and Computer application. It is also intended for any application with low gate charge drive requirements.

### **Applications**

■ Switching application



#### Internal schematic diagram



#### **Order codes**

Part number	umber Marking Package		Packaging
STP40NF10L	P40NF10L	TO-220	Tube

Contents STP40NF10L

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STP40NF10L Electrical ratings

# 1 Electrical ratings

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit	
V <sub>DS</sub>	Drain-source voltage (v <sub>gs</sub> = 0)	100	٧	
V <sub>GS</sub>	Gate- source voltage	±17	V	
I <sub>D</sub>	Drain current (continuous) at T <sub>C</sub> = 25°C	40	Α	
I <sub>D</sub>	Drain current (continuous) at T <sub>C</sub> = 100°C	25	Α	
I <sub>DM</sub> <sup>(1)</sup>	Drain current (pulsed)	160	Α	
P <sub>TOT</sub>	Total dissipation at T <sub>C</sub> = 25°C	150	W	
	Derating factor	1	W/°C	
E <sub>AS</sub> (2)	Single pulse avalanche energy	430	mJ	
T <sub>stg</sub>	Storage temperature	- 65 to 175		
T <sub>j</sub>	Max. operating junction temperature	175	°C	

<sup>1.</sup> Pulse width limited by safe operating area

Table 2. Thermal data

R <sub>thj-case</sub>	Thermal resistance junction-case Max	1	°C/W
R <sub>thj-a</sub>	Thermal resistance junction-ambient Max	62.5	°C/W
T <sub>I</sub>	Maximum lead temperature for soldering purpose	300	°C

<sup>2.</sup> Starting  $T_i$ = 25°C,  $I_D$  = 20A,  $V_{DD}$ =40V

Electrical characteristics STP40NF10L

## 2 Electrical characteristics

(T<sub>CASE</sub>=25°C unless otherwise specified)

Table 3. On/off states

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V <sub>(BR)DSS</sub>	Drain-source Breakdown voltage	$I_D = 250 \mu\text{A},  V_{GS} = 0$	100			V
I <sub>DSS</sub>	Zero gate voltage Drain current (V <sub>GS</sub> = 0)	$V_{DS}$ = Max rating $V_{DS}$ =Max rating, $T_{C}$ =125°C			1 10	µА µА
I <sub>GSS</sub>	Gate-body leakage current (V <sub>DS</sub> = 0)	V <sub>GS</sub> = ±17V			±100	nA
V <sub>GS(th)</sub>	Gate threshold voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1	1.7	2.5	V
R <sub>DS(on)</sub>	Static drain-source on resistance	$V_{GS} = 10V, I_D = 20A$ $V_{GS} = 5V, I_D = 20A$		0.028 0.030	0.033 0.036	Ω

Table 4. Dynamic

Symbol	Parameter Test conditions		Min.	Тур.	Max.	Unit
g <sub>fs</sub> <sup>(1)</sup>	Forward transconductance	V <sub>DS</sub> = 15V <sub>,</sub> I <sub>D</sub> =20A		25		S
C <sub>iss</sub>	Input capacitance			2300		pF
C <sub>oss</sub>	Output capacitance	$V_{DS} = 25V, f = 1 \text{ MHz}, V_{GS} = 0$		290		pF
C <sub>rss</sub>	Reverse transfer capacitance	$V_{GS} = 0$		125		pF
Qg	Total gate charge			46	64	nC
$Q_{gs}$	Gate-source charge	$V_{DD} = 80V, I_D = 40A,$ $V_{GS} = 5V$		12		nC
$Q_{gd}$	Gate-drain charge	·GS = ••		22		nC

<sup>1.</sup> Pulsed: Pulse duration = 300  $\mu$ s, duty cycle 1.5.

Table 5. Switching times

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t <sub>d(on)</sub>	Turn-on delay time Rise time	$V_{DD} = 50$ V, $I_D = 20$ A $R_G = 4.7\Omega V_{GS} = 4.5$ V (see Figure 13)		25 82		ns ns
t <sub>d(off)</sub>	Turn-off-delay time Fall time	$V_{DD} = 50V, I_D = 20A,$ $R_G = 4.7\Omega, V_{GS} = 4.5V$ (see Figure 13)		64 24		ns ns
t <sub>d(off)</sub> t <sub>f</sub> t <sub>c</sub>	Off-voltage Rise Time Fall Time Cross-over time	Vclamp =80V, $I_D$ = 40 A $R_G$ = 4.7 $\Omega$ , $V_{GS}$ = 4.5V (see Figure 15)		51 29 53		ns ns ns

Table 6. Source drain diode

Symbol	Parameter	Test conditions	Min.	Тур.	Max	Unit
I <sub>SD</sub>	Source-drain current				40	Α
I <sub>SDM</sub> <sup>(1)</sup>	Source-drain current (pulsed)				160	Α
V <sub>SD</sub> <sup>(2)</sup>	Forward on voltage	$I_{SD} = 40A, V_{GS} = 0$			1.3	V
t <sub>rr</sub> Q <sub>rr</sub> I <sub>RRM</sub>	Reverse recovery time Reverse recovery charge Reverse recovery current	$I_{SD} = 40A, V_{DD} = 30V$ di/dt = 100A/ $\mu$ s, $T_j = 150$ °C (see Figure 15)		110 467 8		ns nC A

<sup>1.</sup> Pulse width limited by safe operating area.

<sup>2.</sup> Pulsed: Pulse duration = 300  $\mu$ s, duty cycle 1.5%

Electrical characteristics STP40NF10L

### 2.1 Electrical characteristics (curves)

Figure 1. Safe operating area

Figure 2. Thermal impedance

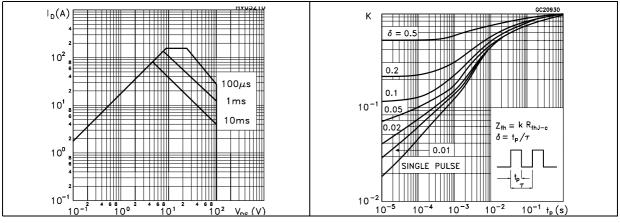


Figure 3. Output characteristics

Figure 4. Transfer characteristics

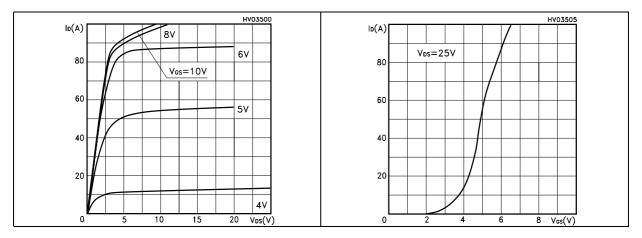


Figure 5. Transconductance

Figure 6. Static drain-source on resistance

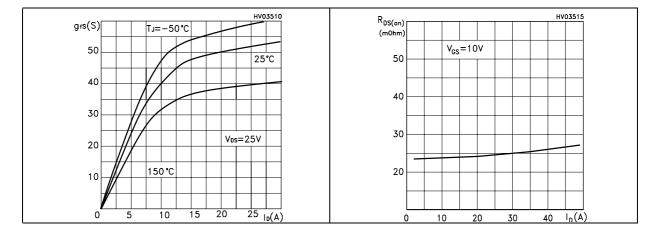


Figure 7. Gate charge vs. gate-source voltage Figure 8. Capacitance variations

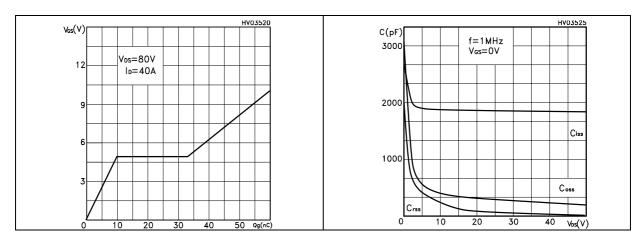


Figure 9. Normalized gate threshold voltage vs. temperature

Figure 10. Normalized on resistance vs. temperature

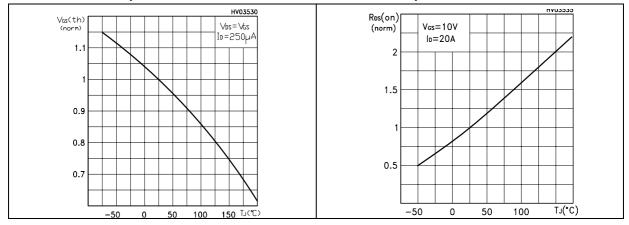
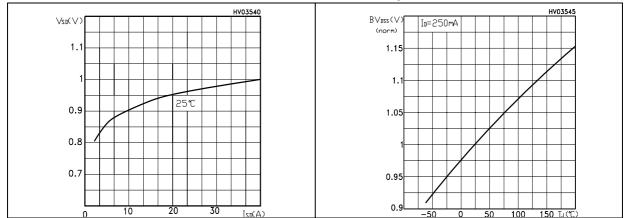


Figure 11. Source-drain diode forward characteristics

Figure 12. Normalized breakdown voltage vs.



Test circuit STP40NF10L

### 3 Test circuit

Figure 13. Switching times test circuit for resistive load

Figure 14. Gate charge test circuit

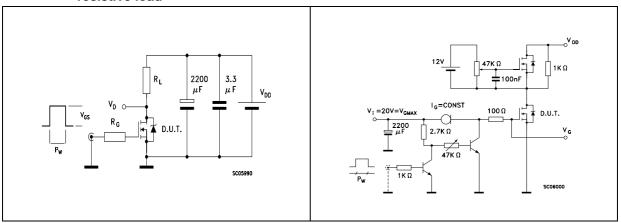


Figure 15. Test circuit for inductive load switching and diode recovery times

Figure 16. Unclamped Inductive load test circuit

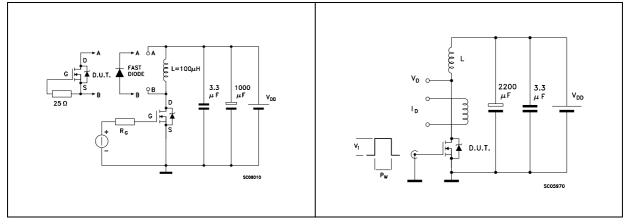
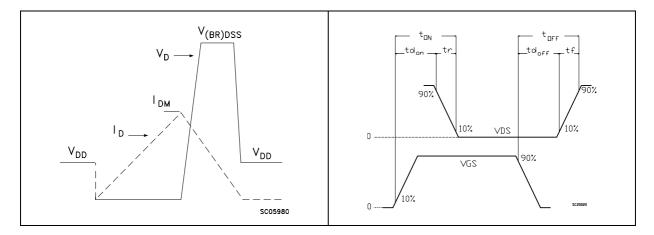


Figure 17. Unclamped inductive waveform

Figure 18. Switching time waveform

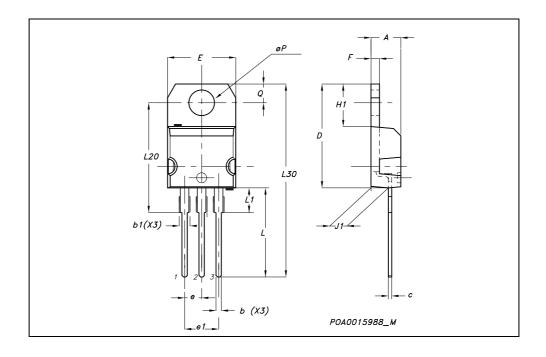


## 4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: <a href="https://www.st.com">www.st.com</a>

#### **TO-220 MECHANICAL DATA**

DIM.		mm.			inch	
DIN.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
Α	4.40		4.60	0.173		0.181
b	0.61		0.88	0.024		0.034
b1	1.15		1.70	0.045		0.066
С	0.49		0.70	0.019		0.027
D	15.25		15.75	0.60		0.620
E	10		10.40	0.393		0.409
е	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.194		0.202
F	1.23		1.32	0.048		0.052
H1	6.20		6.60	0.244		0.256
J1	2.40		2.72	0.094		0.107
L	13		14	0.511		0.551
L1	3.50		3.93	0.137		0.154
L20		16.40			0.645	
L30		28.90			1.137	
øΡ	3.75		3.85	0.147		0.151
Q	2.65		2.95	0.104		0.116



STP40NF10L Revision history

# 5 Revision history

Table 7. Revision history

Date	Revision	Changes
09-Sep-2004	1	First version.
17-Aug-2006	2	The document has been reformatted.
31-Jan-2007	3	Typo mistake on <i>Table 1</i> .

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